

Trans IGBT Chip N-CH 3600V 92A 417mW 3-Pin(3+Tab) ISOPLUS I5-PAK

Manufacturer:	Littelfuse Inc	
Package/Case:	TO-247	
Product Type:	Thyristors	
RoHS:	RoHS Compliant/Lead free	Images are for reference only
Lifecycle:	NRND	Inquiry

General Description

BiMOSFETs are devices, which have combined strengths of MOSFETs and IGBTs. Non-epitaxial construction and new fabrication processes were used in making BiMOSFETs a great success. These high voltage devices are ideal for parallel operation due to the positive voltage temperature coefficient of both of its saturation voltage, and the forward voltage drop of its intrinsic diode. Furthermore, this "free" intrinsic body diode serves as a protection diode, providing an alternative path for the inductive load current during device turn-off, preventing high Ldi/dt voltage transients from inflicting damage to the device.

Key Features	Application	
High power density	Switched-mode and resonant-mode power supplies	
High frequency operation	Uninterruptible Power Supplies (UPS)	
Low conduction losses	Laser and X-ray generators	
MOS gate turn on for drive simplicity	Capacitor discharge circuits	
4000V electrical isolation		
Advantages:	High voltage pulser circuits	
Low gate drive requirements	High voltage test equipment	
Space savings (eliminates multiple series-parallel lower voltage, lower current rated devices)	AC switches	
Easy to mount		

Recommended For You

IXGH48N60C3D1	IXYX100N120C3	IXGH30N60B2D1
Littelfuse Inc	Littelfuse Inc	Littelfuse Inc
TO-247	PLUS247	TO-247

IXYN30N170CV1	IXBH16N170	IXGH60N60C2
Littelfuse Inc	Littelfuse Inc	Littelfuse Inc
Ν	TO-247	TO-247
IXGH48N60A3	IXGN320N60A3	IXGH60N60C3
Littelfuse Inc	Littelfuse Inc	Littelfuse Inc
TO-247	MODULE	TO-247
IXGP20N120A3	IXYR50N120C3D1	IXYH50N65C3D1
Littelfuse Inc	Littelfuse Inc	Littelfuse Inc
TO-220	ISOPLUS247	TO-247
IXGP8N100	IXTQ460P2	IXGR48N60C3D1
Littelfuse Inc	Littelfuse Inc	Littelfuse Inc

TO-247

TO-3P

TO-220